

1. Global joint venture starts operations as WeEn Semiconductors

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As from November 9th, 2015 NXP Semiconductors N.V. and Beijing JianGuang Asset Management Co. Ltd established Bipolar Power joint venture (JV), **WeEn Semiconductors**, which will be used in future Bipolar Power documents together with new contact details.

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Thank you for your cooperation and understanding,

WeEn Semiconductors





1. General description

Planar passivated Silicon Controlled Rectifier (SCR) in a SOT404 (D2PAK) surface mountable plastic package intended for use in applications requiring very high inrush current capability, high thermal cycling performance and high junction temperature capability ($T_{j(max)}$ = 150 °C).

2. Features and benefits

- High bidirectional blocking voltage capability
- High junction operating temperature capability
- High thermal cycling performance
- Planar passivated for voltage ruggedness and reliability
- Surface mountable package
- Very high current surge capability

3. Applications

- Capacitive Discharge Ignition (CDI)
- Crowbar protection
- Inrush protection
- Motor control
- Voltage regulation

4. Quick reference data

Table 1. Quick reference data							
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{DRM}	repetitive peak off- state voltage			-	-	800	V
V _{RRM}	repetitive peak reverse voltage			-	-	800	V
I _{TSM}	non-repetitive peak on- state current	half sine wave; T _{j(init)} = 25 °C; t _p = 10 ms; <u>Fig. 4</u> ; <u>Fig. 5</u>		-	-	210	A
		half sine wave; $T_{j(init)} = 25 \text{ °C};$ $t_p = 8.3 \text{ ms}$		-	-	231	A
Tj	junction temperature			-	-	150	°C





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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _{T(RMS)}	RMS on-state current	half sine wave; T _{mb} ≤ 129 °C; <u>Fig. 2;</u> <u>Fig. 3</u>	-	-	20	A
Static chara	cteristics	·				
I _{GT}	gate trigger current	V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; <u>Fig. 7</u>	-	4.5	32	mA
Dynamic cha	aracteristics	·				_
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 536 V; T _j = 150 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit	300	-	-	V/µs

5. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	к	cathode	mb	A - ∏I K
2	А	anode		G sym037
3	G	gate		
mb	A	mounting base; connected to anode	$\begin{bmatrix} 1 & 2 & 1 \\ 1 & 3 \end{bmatrix}$	
			D2PAK (SOT404)	

6. Ordering information

Table 3. Ordering inf	formation		
Type number	Package		
	Name	Description	Version
TYN20B-800T	D2PAK	plastic single-ended surface-mounted package (D2PAK); 3 leads (one lead cropped)	SOT404

7. Marking

Table 4. Marking codes	
Type number	Marking code
TYN20B-800T	TYN20B-800T

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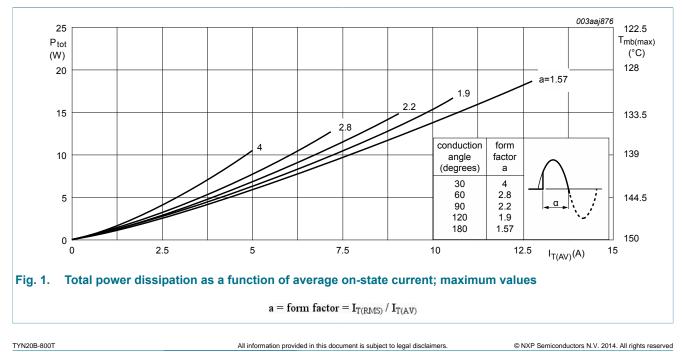
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Limiting values 8.

Table 5. **Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Мах	Unit
V _{DRM}	repetitive peak off-state voltage		-	800	V
V _{RRM}	repetitive peak reverse voltage		-	800	V
I _{T(AV)}	average on-state current	half sine wave; T _{mb} ≤ 129 °C; <u>Fig. 1</u>	-	12.7	А
I _{T(RMS)}	RMS on-state current	half sine wave; $T_{mb} \le 129 \text{ °C}$; Fig. 2; Fig. 3	-	20	A
I _{TSM}	non-repetitive peak on-state current	half sine wave; $T_{j(init)} = 25 \text{ °C};$ t _p = 10 ms; <u>Fig. 4</u> ; <u>Fig. 5</u>	-	210	A
		half sine wave; $T_{j(init)}$ = 25 °C; t_p = 8.3 ms	-	231	A
l ² t	I ² t for fusing	t _p = 10 ms; sine-wave pulse	-	220.5	A ² s
dl _T /dt	rate of rise of on-state current	I _T = 40 A; I _G = 200 mA; dI _G / dt = 200 mA/μs	-	50	A/µs
I _{GM}	peak gate current		-	5	А
V _{RGM}	peak reverse gate voltage		-	5	V
P _{GM}	peak gate power		-	20	W
P _{G(AV)}	average gate power	over any 20 ms period	-	1	W
T _{stg}	storage temperature		-40	150	°C
Tj	junction temperature		-	150	°C

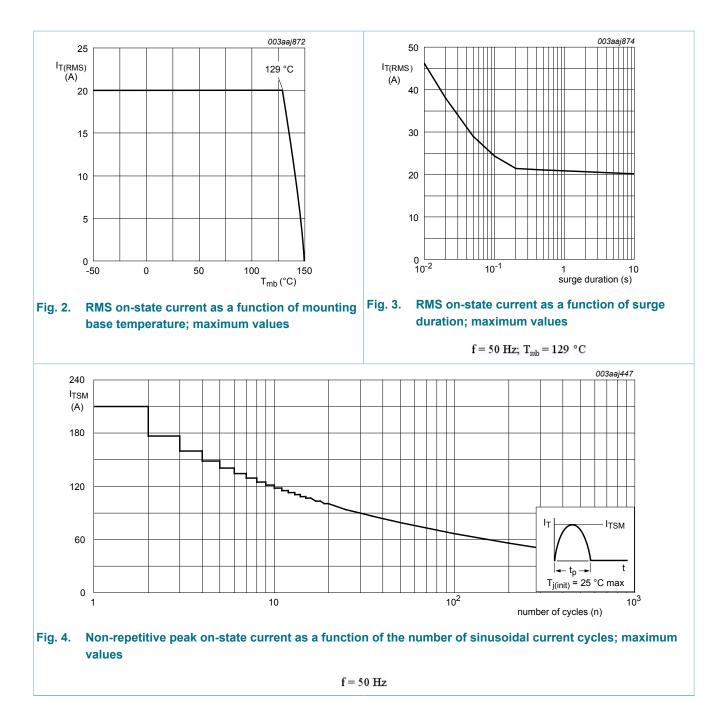


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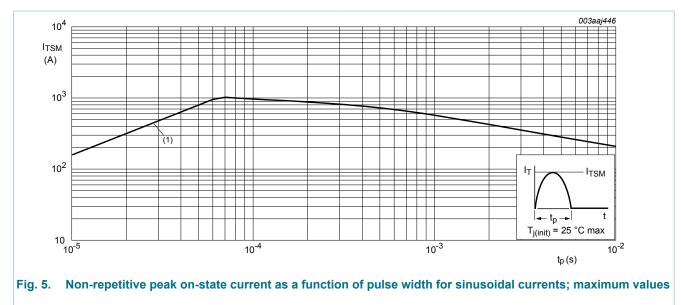
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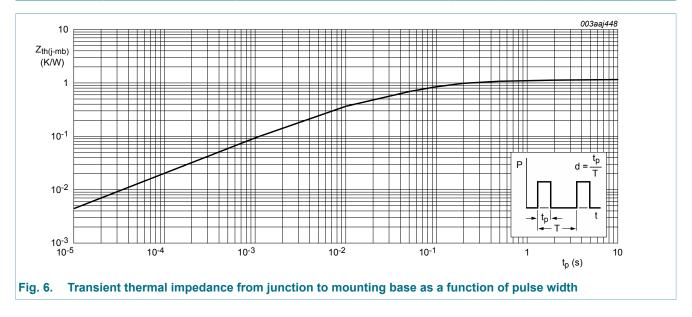
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 $t_p \leq 10 ms;$ (1) $dI_T / dt limit$

9. Thermal characteristics

Table 6. The	rmal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	<u>Fig. 6</u>	-	-	1.1	K/W
R _{th(j-a)}	thermal resistance from junction to ambient	minimum footprint, FR4 board	-	55	-	K/W



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Product data sheet

21 March 2014

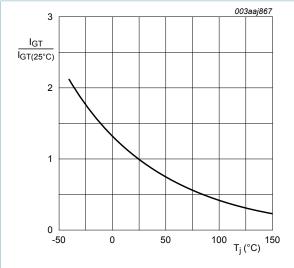
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10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics	· · ·	I	_		
I _{GT}	gate trigger current	V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; <u>Fig. 7</u>	-	4.5	32	mA
IL	latching current	V_D = 12 V; I _G = 0.1 A; T _j = 25 °C; Fig. 8	-	21	60	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u>	-	16	40	mA
V _T	on-state voltage	I _T = 32 A; T _j = 25 °C; <u>Fig. 10</u>	-	1.2	1.5	V
V _{GT}	gate trigger voltage	V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; Fig. 11	-	0.7	1.3	V
		V _D = 400 V; I _T = 0.1 A; T _j = 150 °C; Fig. 11	0.2	0.4	-	V
I _D	off-state current	V _D = 800 V; T _j = 150 °C	-	0.2	1	mA
I _R	reverse current	V _R = 800 V; T _j = 150 °C	-	0.2	1	mA
Dynamic cl	naracteristics	· · · · · ·	1			
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 536 V; T _j = 150 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit	300	-	-	V/µs

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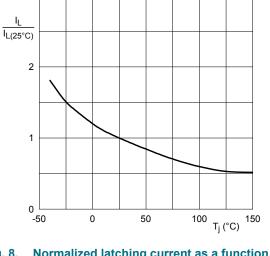


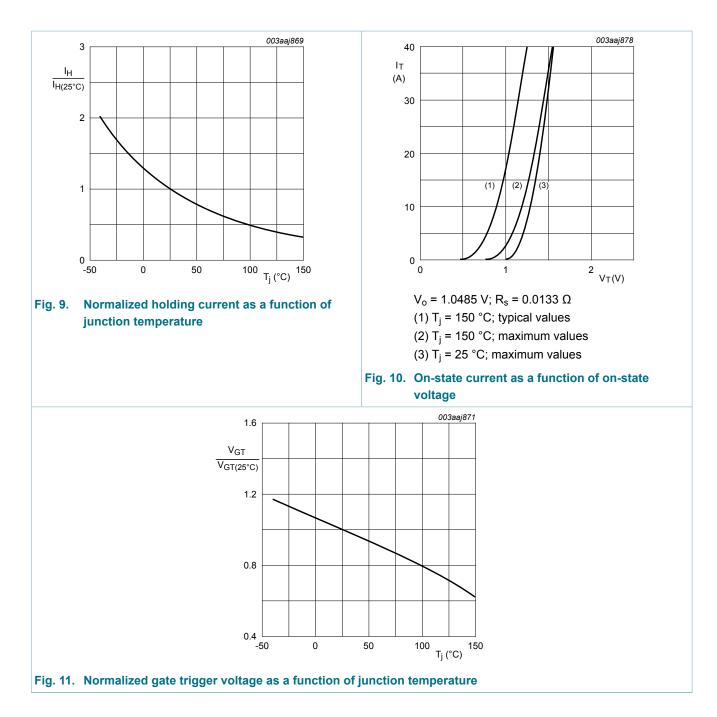
Fig. 7. Normalized gate trigger current as a function of Junction temperature



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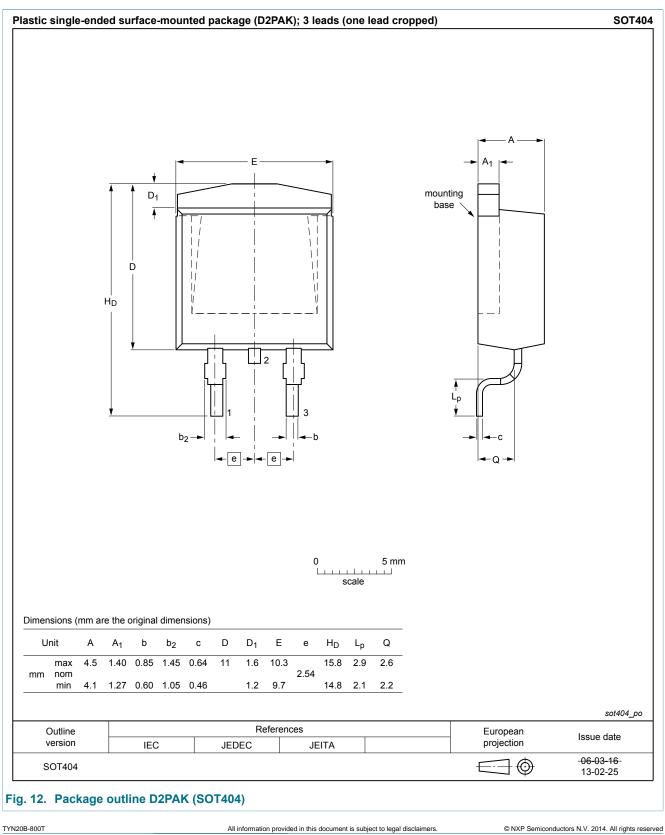
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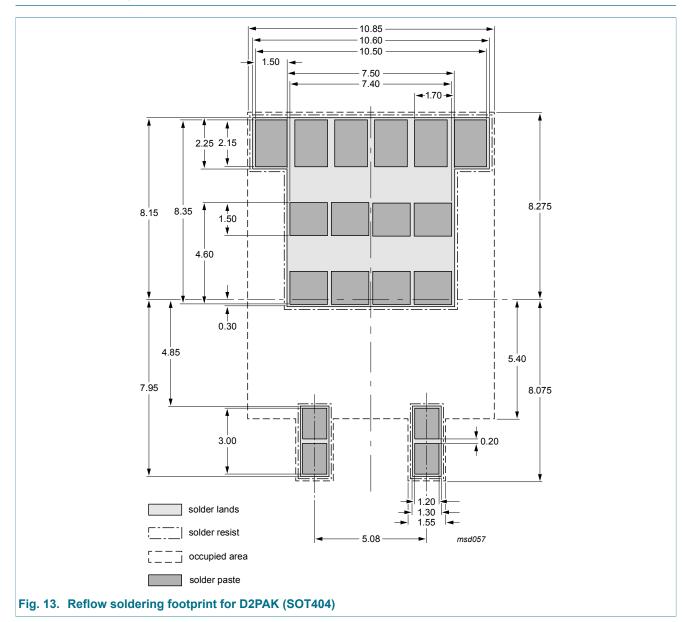
11. Package outline



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12. Soldering



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13. Legal information

13.1 Data sheet status

Document status [1][2]	Product status [<u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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